
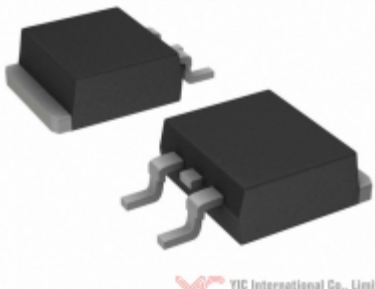



	<h2 style="color: red;">FQB3N40TM</h2>
	<p><b>Hersteller-Teilenummer:</b> <a href="#">FQB3N40TM</a></p> <hr/> <p><b>Hersteller / Marke:</b> <a href="#">AMI Semiconductor / ON Semiconductor</a></p> <hr/> <p><b>Teil der Beschreibung:</b> MOSFET N-CH 400V 2.5A D2PAK</p> <hr/> <p><b>Datenblätter:</b>  <a href="#">FQB3N40TM.pdf</a></p> <hr/> <p><b>RoHs Status:</b> Bleifrei / RoHS-konform</p> <hr/> <p><b>Lagerzustand:</b> New original, 34104 pcs Stock Available.</p> <hr/> <p><b>Liefern von:</b> Hong Kong</p> <hr/> <p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

### Spezifikationen

Teilenummer	<a href="#">FQB3N40TM</a>
Hersteller	<a href="#">AMI Semiconductor / ON Semiconductor</a>
Beschreibung	MOSFET N-CH 400V 2.5A D2PAK
Kategorie	<a href="#">Diskrete Halbleiterprodukte &gt; Transistoren-FETs,</a>
Teilstatus	34104 pcs Stock
detaillierte Beschreibung	N-Channel 400V 2.5A (Tc) 3.13W (Ta), 55W (Tc)
Serie	QFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-263-3, D <sup>2</sup> Pak (2 Leads + Tab), TO-263AB
Supplier Device-Gehäuse	D <sup>2</sup> PAK (TO-263AB)
Verlustleistung (max)	3.13W (Ta), 55W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (V <sub>dss</sub> )	400V
Strom - Ununterbrochener Abfluss (I <sub>d</sub> ) bei 25 ° C	2.5A (Tc)
R <sub>ds On</sub> (Max) @ I <sub>d</sub> , V <sub>gs</sub>	3.4 Ohm @ 1.25A, 10V
V <sub>GS</sub> (th) (Max) @ I <sub>d</sub>	5V @ 250µA
Gate Charge (Q <sub>g</sub> ) (Max) @ V <sub>gs</sub>	7.5nC @ 10V
Eingabekapazität (C <sub>iss</sub> ) (Max) @ V <sub>ds</sub>	230pF @ 25V
Antriebsspannung (Max R <sub>ds On</sub> , Min R <sub>ds On</sub> )	10V
V <sub>gs</sub> (Max)	±30V
Verpackung	Tape & Reel (TR)
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)


FQB3N40TM ist neu im Original, Suche FQB3N40TM Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FQB3N40TM AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage FQB3N40TM: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

 <p><b>FQB3N60</b> VB FQB3N60 VB</p>	 <p><b>FQB3N25TM</b> Fairchild/ON Semiconductor MOSFET N-CH 250V 2.8A D2PAK</p>	 <p><b>FQB3N60C</b> FCS FQB3N60C FCS</p>	 <p><b>FQB3N30TM</b> Fairchild/ON Semiconductor MOSFET N-CH 300V 3.2A D2PAK</p>
 <p><b>FQB3N40TM</b> Fairchild/ON Semiconductor MOSFET N-CH 400V 2.5A D2PAK</p>	 <p><b>FQB3N25TM</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 250V 2.8A D2PAK</p>	 <p><b>FQB3N60CTM</b> Fairchild/ON Semiconductor MOSFET N-CH 600V 3A D2PAK</p>	 <p><b>FQB3N60CTM</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 600V 3A D2PAK</p>

### heiße Teile

Mehr

 FQB32N20	 FQB32N20C	 FQB32N20CTM	 D FQB32N20CTM	 FQB32N30
 FQB33N10	 FQB33N10L	 D FQB33N10LTM	 FQB33N10LTM	 FQB33N10TM
 FQB33N10TM	 FQB34N20	 FQB34N20L	 FQB34N20LTM	 FQB34N20LTM
 D FQB34N20TM	 FQB34N20TM_AM002	 FQB34P10	 FQB34P10TM	 FQB34P10TM
 FQB34P10TM_F085	 FQB3N25TM	 FQB3N25TM	 FQB3N30TM	 FQB3N30TM
 FQB3N40TM	 FQB3N60C	 D FQB3N80TM	 FQB3N80TM	 FQB3N90TM
 FQB3N90TM	 D FQB3P20TM	 FQB3P20TM	 FQB3P50TM	 FQB3P50TM
 FQB44N10	 FQB44N10TM	 FQB44N10TM	 FQB46N15	 FQB46N15TM
 FQB47P06	 FQB47P06TM	 FQB4N20L	 D FQB4N20LTM	 FQB4N20LTM
 FQB4N20TM	 FQB4N20TM	 FQB4N25TM	 FQB4N25TM	 FQB4N20TM

Contact us: [Info@Y-IC.com](mailto:Info@Y-IC.com)

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